

NON-AMPLIFIED HIGH SPEED PHOTODETECTOR USER'S GUIDE

Thank you for purchasing your Non-amplified High Speed Photodetector. This user's guide will help answer any questions you may have regarding the safe use and optimal operation of your Photodetector.

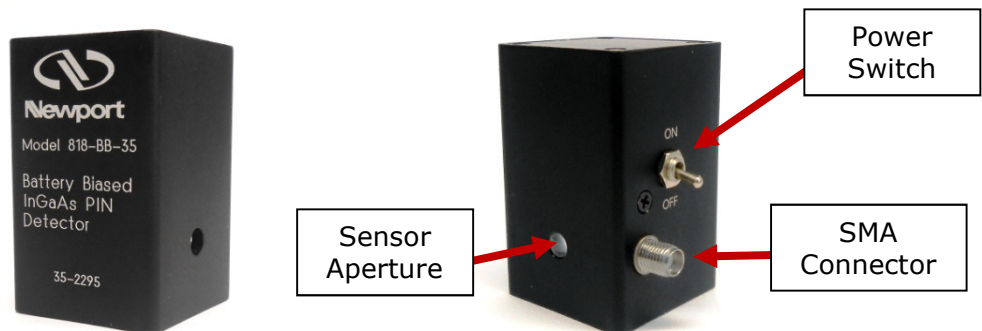
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I. Non-amplified High Speed Photodetector Overview

The Non-amplified High Speed Photodetectors contain PIN photodiodes that utilize the photovoltaic effect to convert optical power into an electrical current. Figure 1 below identifies the main elements of your Photodetector.

Figure 1: Non-amplified High Speed Photodetector



When terminated into 50Ω into an oscilloscope, the pulsewidth of a laser can be measured. When terminated into a spectrum analyzer, the frequency response of a laser can be measured.

II. Operation of your Non-amplified High Speed Photodetector

- Caution: Eye safety precautions must be followed when utilizing any equipment used in the vicinity of laser beams. Laser beams may reflect from the surface of the detector or the optical mount and caution must be exercised.
- Mount the detector to an optical stand by the mounting holes on the bottom of the detector housing.
- Adjust the voltage of the oscilloscope to 20mV/division before connecting the detector.
- Connect the detector to the oscilloscope using a coaxial cable designed for 10GHz operation.

- E. Use the 50Ω termination input of the oscilloscope.
- F. After being certain that the damage threshold of the detector is not exceeded, place the detector in the center of the laser beam.
- G. There is an internal 50Ω resistor at the output of the photodiode. This will cause the output current to your test equipment to be half that of the photodiode output. For example, the output to your equipment will be 450μA for a 1mW optical input at 0.9A/W.

III. Troubleshooting

A. No signal is seen the first time the detector is used.

1. Is the power switch on?
2. Be certain that the signal is not high off scale on the oscilloscope.
3. Is the wavelength of the laser within the spectral range of the detector?
4. Has a 50Ω termination input been used?
5. Try moving the detector within the laser beam.
6. Is there enough light (see sensitivity spec on the data sheet) incident on the detector to generate a signal? The detector's small active area makes alignment somewhat difficult.

B. A signal has been previously obtained, but not currently.

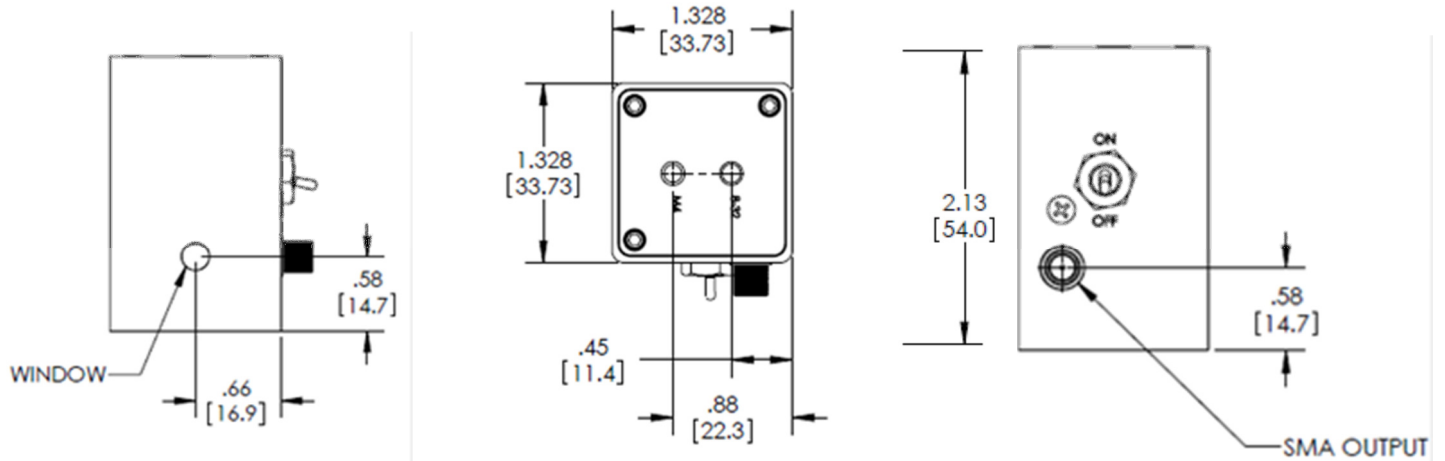
1. Try steps listed under A.
2. Inspect the active area of the photodiode for any signs of damage.
3. Test the power supply:
 - a. Units with internal batteries will typically operate for several years, but operation with CW or high rep rate lasers can drain the batteries much faster. **If a load is present at the output, current will be drawn from the batteries, so disconnect the BNC when not in use.** Remove top cover to replace the 3V lithium cells with Duracell Model DL2430, positive side down.
 - b. Units with an external power supply should at least receive the voltage that is printed on the plug.

C. Increasing the power incident on the detector does not result in a higher voltage signal on the oscilloscope:

1. The detector is probably saturated. You should lower the power incident on the detector to a level below the saturation point.

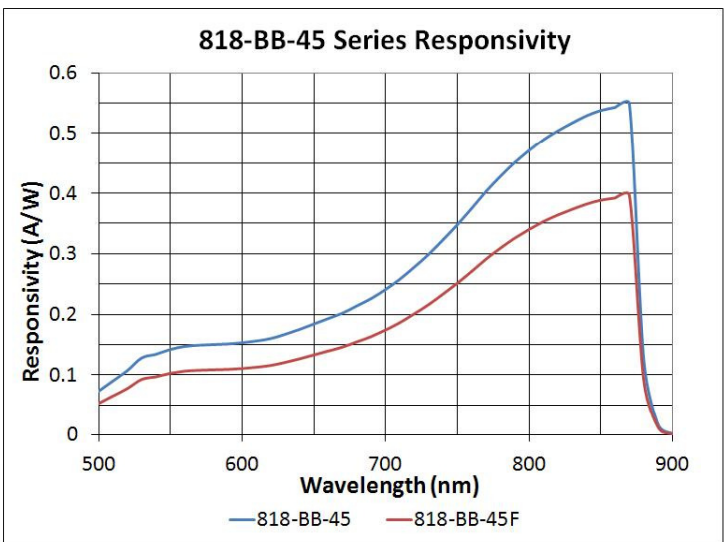
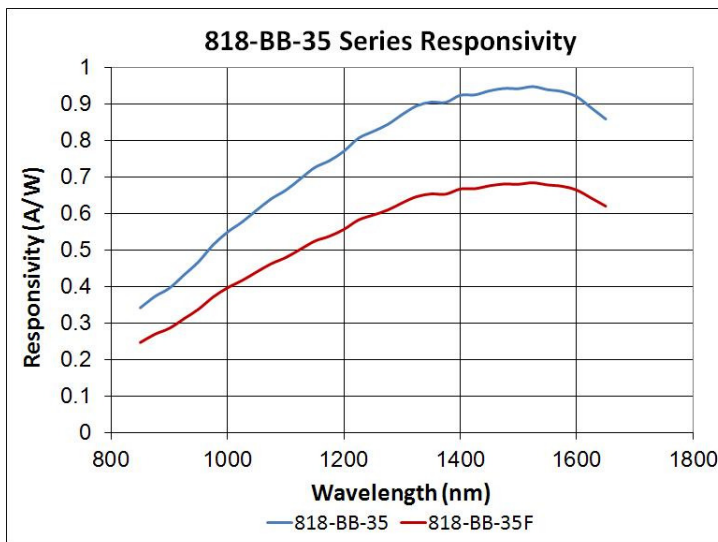
IV. Drawings: Non-amplified High Speed Photodetectors

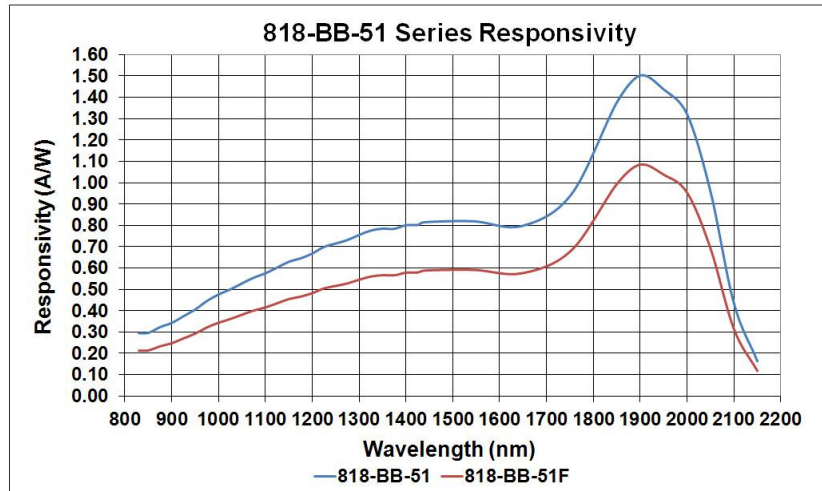
A. 818-BB-35, 818-BB-45, 818-BB-51 Dimensions:



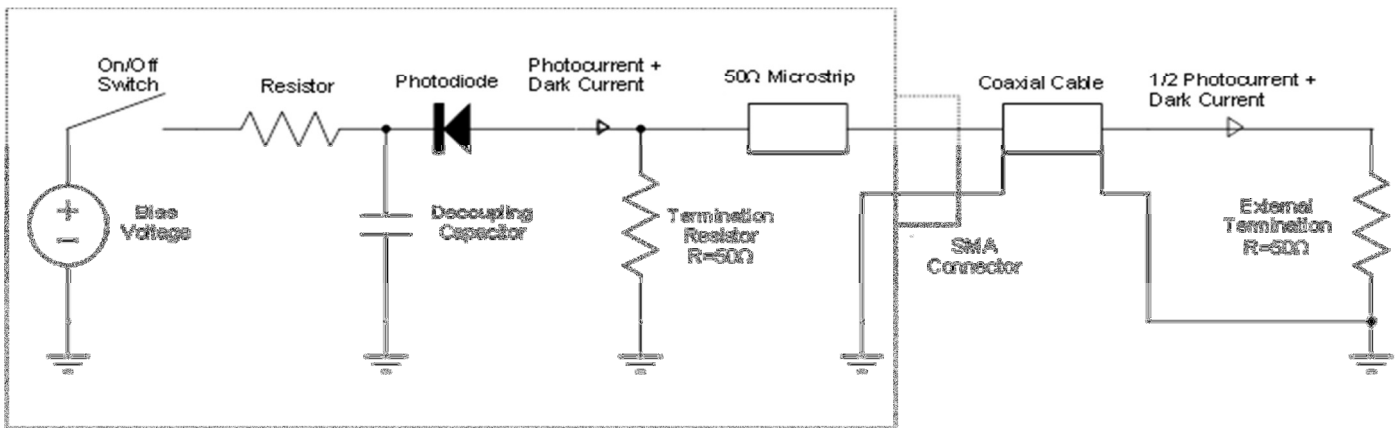
V. Specifications: Non-amplified High Speed Photodetectors

Part No. (Model)	818-BB-35	818-BB-45	818-BB-51
Rise Time/Fall Time (ps)	<25/<25	<30/<30	28
Responsivity (A/W)	>0.90 at 1300nm	0.53 at 830nm	1.3 at 2000nm
Power Supply	6V battery/5V external	3V battery/5V external	3V battery/5V external
Spectral Range (nm)	830-1650	500-890	830-2150
Bandwidth	>15GHz	>12.5GHz	>12.5GHz
Active Area Diameter (μm)	32	60	40
Dark Current	<3nA	<0.5nA	<1μA
Acceptance Angle (1/2 angle)	15°	15°	20°
Noise Equivalent Power (pW/√Hz)	<0.03 at 1300nm	<0.02 at 830nm	<0.44 at 2000nm
Mounting (Tapped Hole)	8-32 or M4	8-32 or M4	8-32 or M4
Output Connector	SMA	SMA	SMA





VI. Schematics: Non-amplified High Speed Photodetectors



VII. Glossary of Terms

Bandwidth: The range of frequencies from 0Hz (DC) to the frequency at which the amplitude decreases by 3dB. Bandwidth and rise time can be approximately related by the equation:
 $\text{Bandwidth} \approx 0.35/\text{rise time}$ for a Gaussian pulse input.

Bias Voltage: The photodiode's junction capacitance can be modified by applying a reverse voltage. The bias voltage reduces the junction capacitance, which causes the photodiode to have a faster response.

Dark Current: When a termination is present, a dark current (nA range) will flow if the photodiode is biased. Disconnecting the coaxial cable will prevent this current from flowing.

Decoupling Capacitor: Maintains bias voltage when fast pulses cause the battery voltage to reduce (this would slow the response time of the photodiode); the capacitor allows the battery to recover to its initial voltage. It also acts as a filter for external power supplies.

Noise Equivalent Power (NEP): A function of responsivity and dark current and is the minimum optical power needed for an output signal to noise ratio of 1. Dark current is the current that flows through a reverse biased photodiode even when light is not present, and is typically on the order of nA. Shot noise (I_{shot}) is a source of noise generated in part by dark current; in the case of reversed biased

diodes it is the dominant contributor. NEP is calculated from shot noise and responsivity. For example, for a responsivity @ 830nm = 0.5 A/W:

$$Shot_Noise = \sqrt{2qI_d} = \sqrt{2(1.6 \times 10^{-19} \text{ As})(20 \times 10^{-9} \text{ A})} = 0.08 \text{ pA} \sqrt{s} = 0.08 \text{ pA} / \sqrt{\text{Hz}}$$

$$NEP = I_{shot} / R_{830\text{nm}} = \frac{0.08 \text{ pA}}{\sqrt{\text{Hz}}} * \frac{\text{W}}{0.5 \text{ A}} = 0.16 \text{ pW} / \sqrt{\text{Hz}}$$

q = charge on an electron

Photodiode: Converts photons into a photocurrent.

Resistor: Protects the photodiode from excessive current. This could occur if an external power supply was too high in voltage, or if its polarity were reversed; this happens when a customer uses their own power supply.

Responsivity: In amps per watt (A/W), responsivity is the current output of the photodiode for a given input power, and is determined by the diode structure. Responsivity varies with wavelength and diode material.

Rise Time/Fall Time: Rise Time is the time taken by a signal to change from a specified low value to a specified high value. Fall Time is the time taken for the amplitude of a pulse to decrease from a specified value to another specified value. A larger junction capacitance will slow the detector's response time.

SMA Connector: Used to connect the customer's coaxial cable for high frequencies.

Termination Resistor (50Ω): Reduces signal reflections and balances the 50Ω microstrip/coaxial cable lines. As a result, half the photodiode current is lost to the internal resistor.